# High Voltage Transistors NPN Silicon

### Features

• Pb–Free Package is Available\*

### MAXIMUM RATINGS

Rating	Symbol	BF420	BF422	Unit
Collector – Emitter Voltage	V <sub>CEO</sub>	300	250	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	300	250	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	5.	.0	Vdc
Collector Current – Continuous	۱ <sub>C</sub>	5	0	mAdc
Collector Current – Peak	I <sub>CM</sub>	10	00	mA
Total Device Dissipation (Note 1) @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	83 6		mW mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to	o +150	°C

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction–to–Ambient	$R_{\theta JA}$	150	°C/W
Thermal Resistance, Junction-to-Lead	$R_{\theta JL}$	68	°C/W

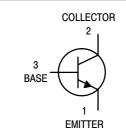
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

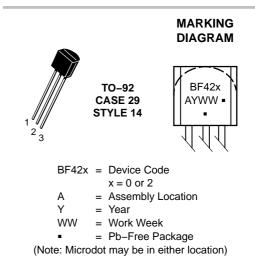
1. Mounted on a FR4 board with 200 mm<sup>2</sup> of 1 oz copper and lead length of 5 mm.



### **ON Semiconductor®**

http://onsemi.com





### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>			
BF420ZL1	TO-92	2000/Ammo Box			
BF420ZL1G	TO–92 (Pb–Free)	2000/Ammo Box			
BF422	TO-92	5000 Units/Box			
BF422G	TO-92 (Pb-Free)	5000 Units/Box			
BF422RL1	TO-92	2000/Tape & Reel			
BF422RL1G	TO–92 (Pb–Free)	2000/Tape & Reel			
BF422ZL1	TO-92	2000/Ammo Pack			
BF422ZL1G	TO–92 (Pb–Free)	2000/Ammo Pack			

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## BF420, BF422

### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = $25^{\circ}$ C unless otherwise noted)

Characteristic		Symbol	Min	Мах	Unit	
OFF CHARACTERISTICS						
Collector – Emitter Breakdown Voltage (Note 1) ( $I_C = 1.0 \text{ mAdc}, I_B = 0$ )	BF420 BF422	V <sub>(BR)CEO</sub>	300 250		Vdc	
Collector – Base Breakdown Voltage ( $I_C = 100 \ \mu Adc, I_E = 0$ )	BF420 BF422	V <sub>(BR)CBO</sub>	300 250		Vdc	
Emitter – Base Breakdown Voltage ( $I_E = 100 \ \mu Adc, I_C = 0$ )	BF420 BF422	V <sub>(BR)EBO</sub>	5.0 5.0		Vdc	
Collector Cutoff Current ( $V_{CB} = 200 \text{ Vdc}, I_E = 0$ )	BF420 BF422	I <sub>CBO</sub>		0.01	μAdc	
Emitter Cutoff Current ( $V_{EB} = 5.0 \text{ Vdc}, I_C = 0$ )	BF420 BF422	I <sub>EBO</sub>		100 -	nAdc	
ON CHARACTERISTICS						
DC Current Gain (I <sub>C</sub> = 25 mAdc, V <sub>CE</sub> = 20 Vdc)	BF420 BF422	h <sub>FE</sub>	50 50		-	
Collector – Emitter Saturation Voltage ( $I_C = 20 \text{ mAdc}, I_B = 2.0 \text{ mAdc}$ )		V <sub>CE(sat)</sub>	_	0.5	Vdc	
Base – Emitter Saturation Voltage ( $I_C = 20 \text{ mAdc}, I_B = 2.0 \text{ mAdc}$ )		V <sub>BE(sat)</sub>	-	2.0	Vdc	
SMALL-SIGNAL CHARACTERISTICS					•	

Current Gain – Bandwidth Product (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc, f = 20 MHz)	f <sub>T</sub>	60	-	MHz
Common Emitter Feedback Capacitance ( $V_{CB} = 30 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz}$ )	C <sub>re</sub>	-	1.6	pF

1. Pulse Test: Pulse Width  $\leq$  300 µs; Duty Cycle  $\leq$  2.0%.

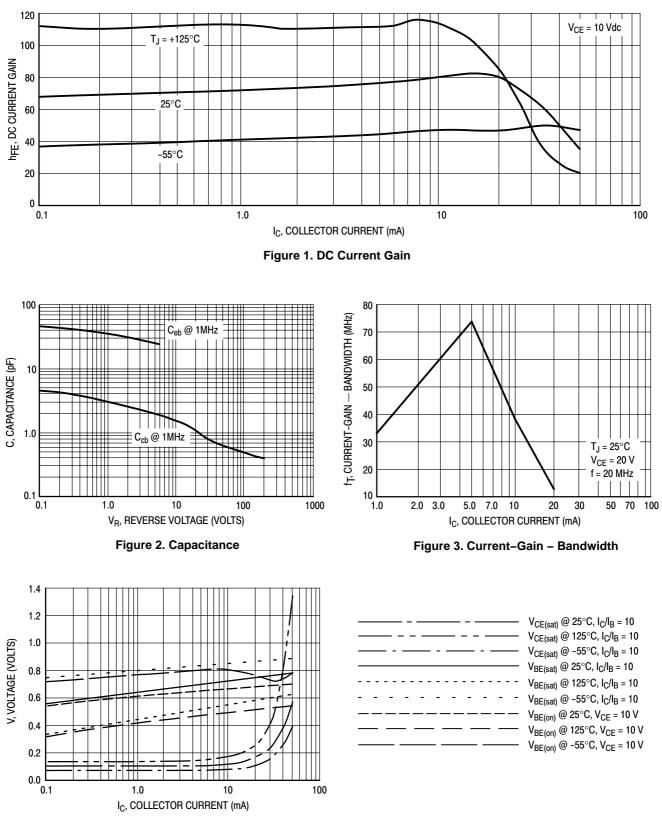
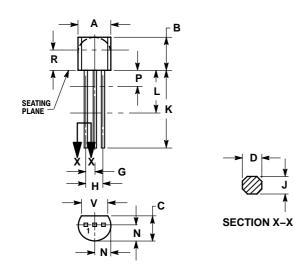


Figure 4. "ON" Voltages

### PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 029-11 **ISSUE AL** 



NOTES 1.

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- 2. 3.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. 4.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

STYLE 14: PIN 1. EMITTER

2. COLLECTOR

3. BASE

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